Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Ma	מנקו ומו.
Metal	
Overall Leng	
0.185 inches	
Terminal Le	-
0.500 inches	
Overall Dian	
0.370 inches	
	onic Device Engineering Council/jedec/case Outline Designation:
To-99	
	Name And Quantity:
2 transistor	
Mounting Mo	etnoa:
Terminal	
	cle Diameter:
0.100 inches	
Features Pro	
Hermetically	
	tor Material:
Silicon all tra	
	ng In Volts Per Characteristic:
	own voltage, collector-to-base, emitter open all transistor
	ng Per Characteristic:
	peres source cutoff current all transistor
	g Per Characteristic:
	all-signal input power, common-collector preset all transistor
	perating Tempurature Per Measurement Point:
•	es celsius ambient air and 150.0 degrees celsius junction
Special Feat	
-	ion configuration transistor npn
	pe And Quantity:
8 uninsulated	1 wire lead
Shelf Life:	
N/a	
Unit Of Meas	sure:
Demilitariza	tion:
No 	
Fiig:	
A110a0	